

High-efficiency spin-resolved ARPES of a topological insulator with the spin-TOF analyzer



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Tech. / Fab. Support

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Scott DiMaggio (ALS)

Adrian Williams (ALS)

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Monroe Thomas (ALS)

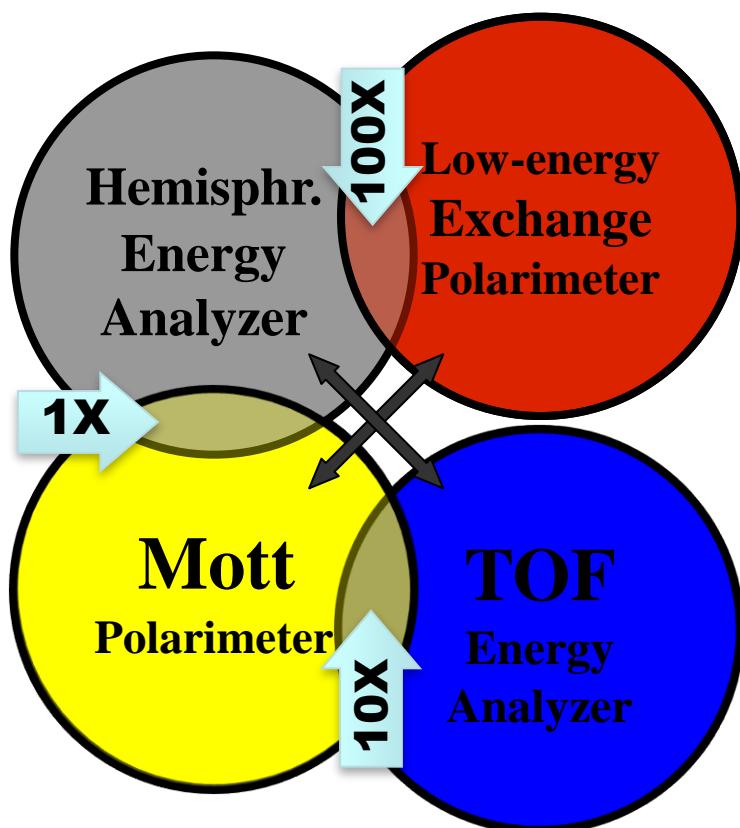
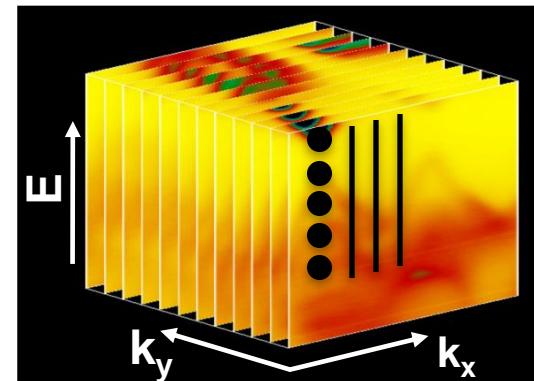


Spin resolution & efficiency

“Standard” ARPES : high speed 2D data acquisition

Efficiency \leftrightarrow resolution, scope

Spin analysis: (1) low efficiency (FOMs $\sim 10^{-4}$)
(2) “single” channel



Hemispherical Energy Analyzer

+ Mott scattering polarimeter

D.-J. Huang, *et al.*, Rev. Sci. Instrum. (1993) (U. Texas)

A.V. Fedorov, *et al.*, J. El. Spectr. Rel. Phen. (1998) (BNL)

G. Ghiringhelli, *et al.*, Rev. Sci. Instrum. (1999) (ESRF)

M. Hoesch, *et al.*, J. El. Spectr. Rel. Phen. (2002) (SLS)

Hemispherical Energy Analyzer

+ Low Energy Exchange scattering polarimeter

F.U. Hillebrecht, *et al.*, Rev. Sci. Instrum. (2002) (Düsseldorf)

R. Bertacco, *et al.*, Rev. Sci. Instrum. (2002) (Milan)

T. Okuda, *et al.*, Rev. Sci. Instrum. (2008) (SRL, Tokyo)

A. Winkelmann, *et al.*, Rev. Sci. Instrum. (2008) (Max-Planck)

Time-of-Flight Analyzer

+ Mott scattering polarimeter

N. Müller, *et al.*, J. El. Spectr. Rel. Phen. (1995) (BESSY)

G. Snell, *et al.*, Rev. Sci. Instrum. (2000) (U. W. Mich., ALS)

L. Moreschini, *et al.*, Rev. Sci. Instrum. (2008) (ESRF)

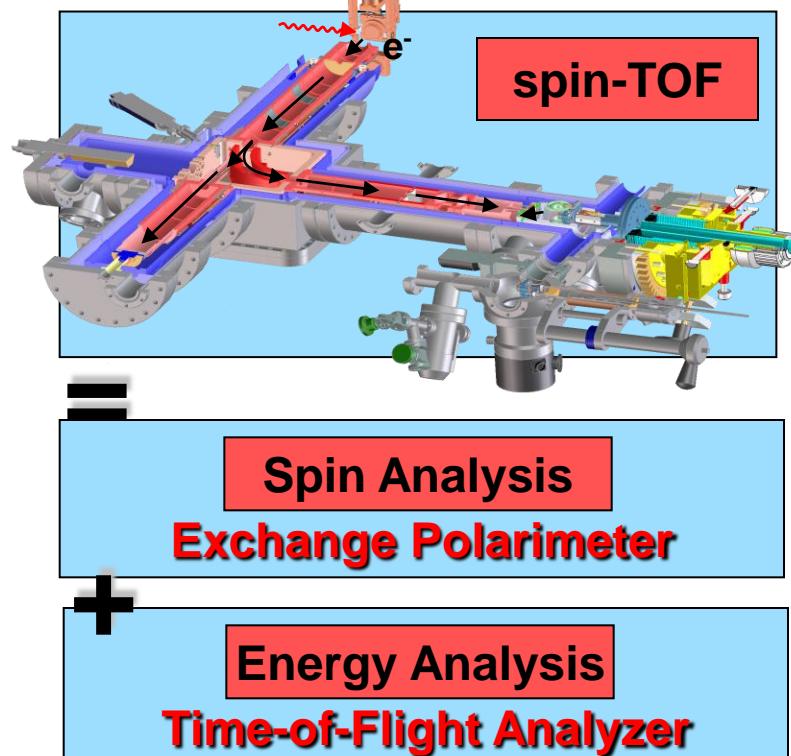
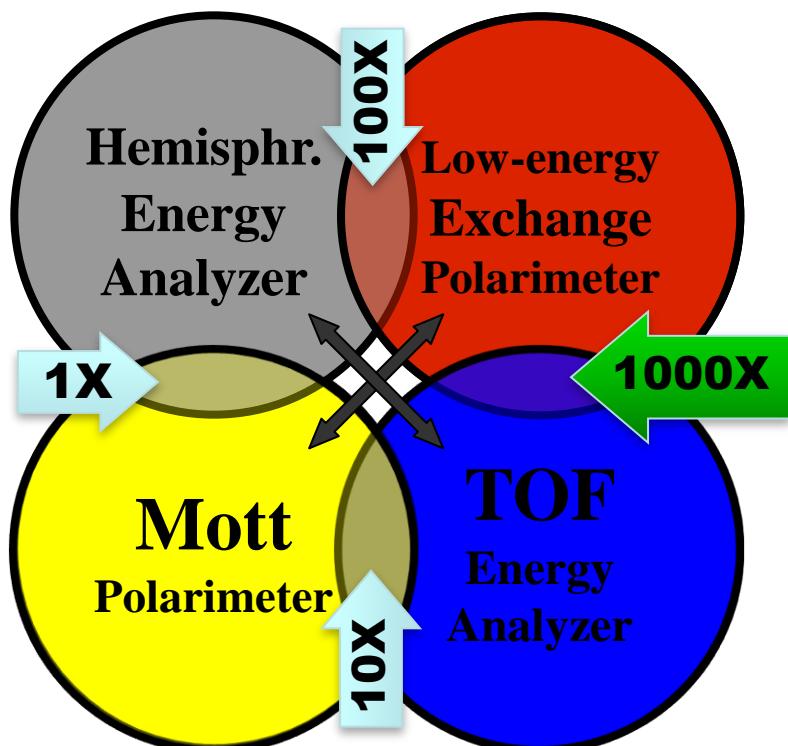
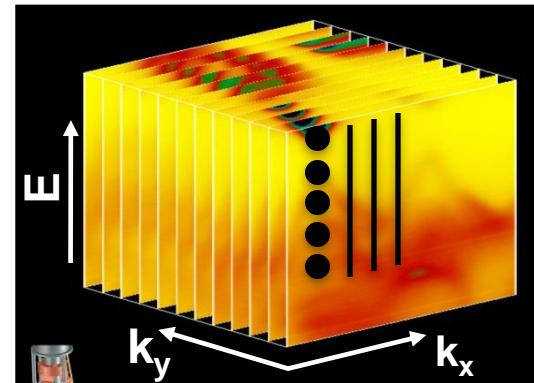
C.M. Cacho, *et al.*, Rev. Sci. Instrum. (2009) (Trieste)

Spin resolution & efficiency

“Standard” ARPES : high speed 2D data acquisition

Efficiency \leftrightarrow resolution, scope

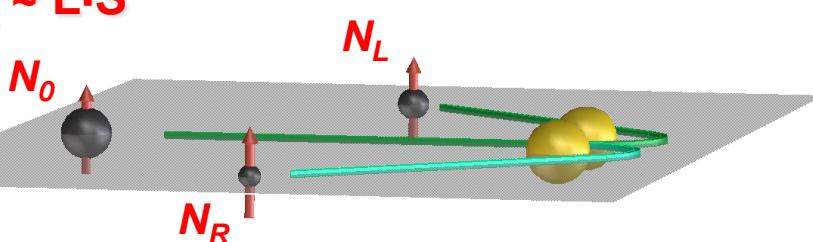
- Spin analysis:
- (1) low efficiency (FOMs $\sim 10^{-4}$)
 - (2) “single” channel



Spin polarimeter efficiency

$$H_{\text{int}} \sim L \cdot S$$

Mott polarimetry



Requires: $\geq 20 \text{ keV} \rightarrow N \ll N_0$

$$S_{\text{eff}} \sim 0.20 \quad N/N_0 \sim 0.002 \quad FOM \sim 1 \times 10^{-4}$$

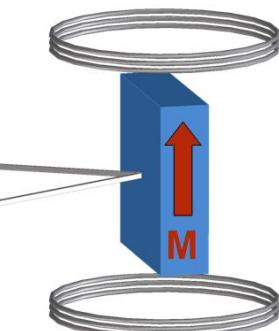
resolving power: **Sherman function**

$$S_{\text{eff}} = \frac{1}{P} \frac{N_L - N_R}{N_R + N_L} \quad P = \frac{1}{S_{\text{eff}}} \frac{N_L - N_R}{N_R + N_L}$$

Overall performance: **figure of merit**

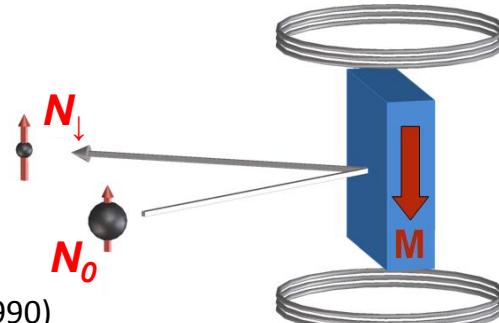
$$FOM = S_{\text{eff}}^2 \frac{N_L + N_R}{N_0}$$

$$H_{\text{int}} \sim M \cdot S$$



$\sim 10 \text{ eV}$

Exchange polarimetry



Target system:
50 ML Co/W(110)

$$S_{\text{eff}} \sim 0.12 \rightarrow 0.25$$

$$N/N_0 \sim 0.065$$

$$FOM \sim 1 \times 10^{-3} \rightarrow 4 \times 10^{-3}$$

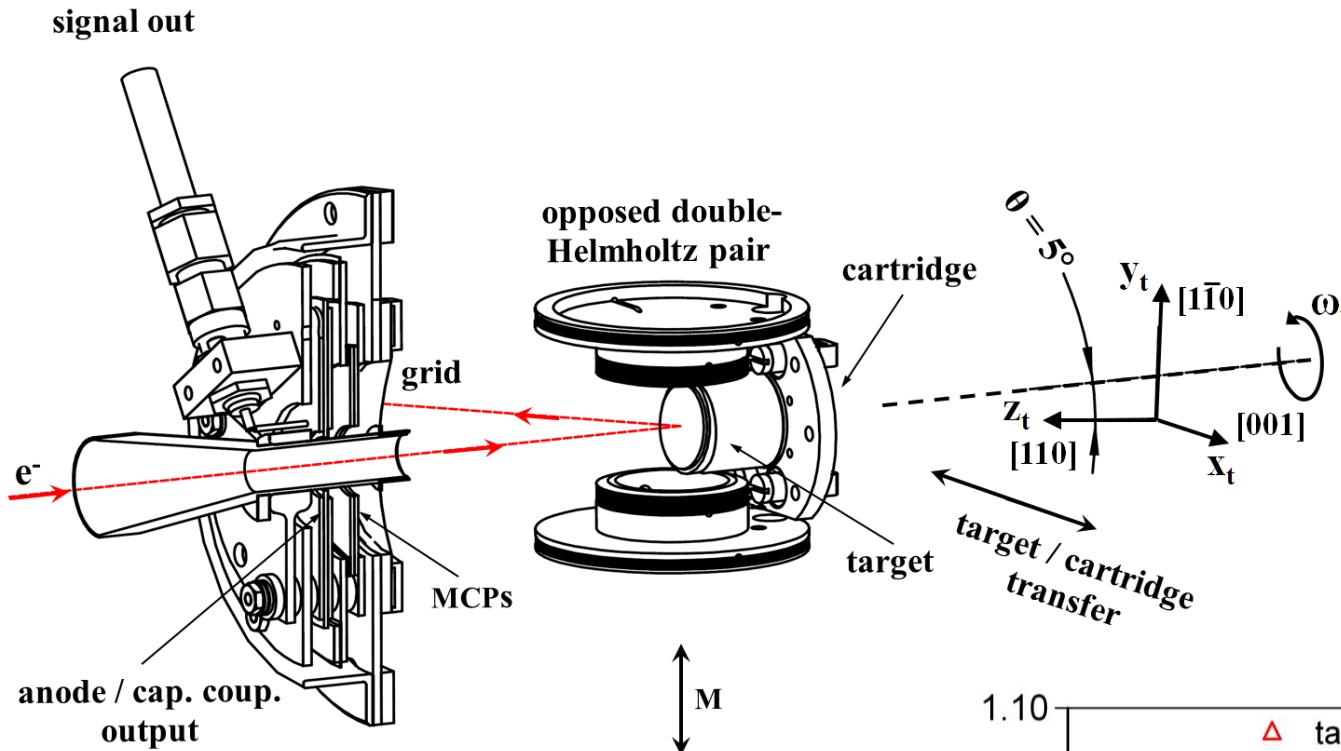
R.J. Celotta, et al., PRL **43**, 728 (1979)

D. Tillmann, et al., Z. Phys. B **77**, 1 (1989)

M. Hammond, et al., Vacuum **41**, 500 (1990)

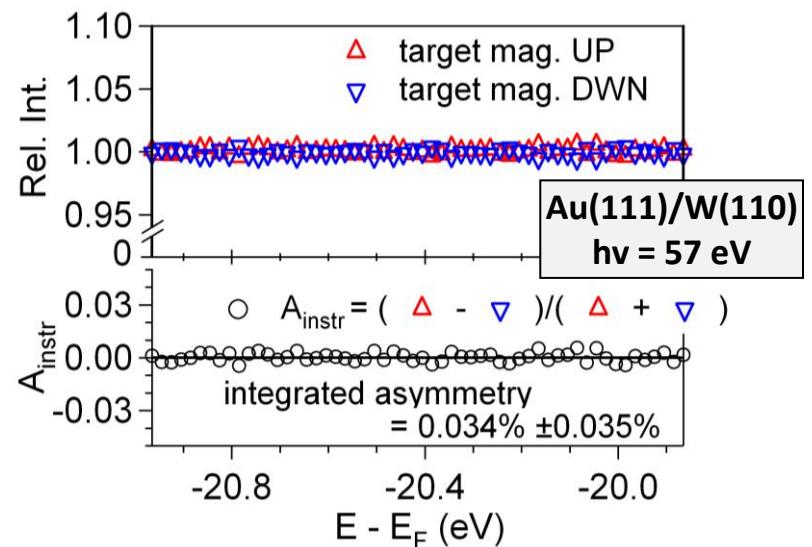
F.U. Hillebrecht, et al., PRL **65**, 2450 (1990)

Polarimeter design



Key Features:

- High-speed detection - $\Delta t < 200$ ps
- Minimal scattering angle, θ
- Versatile, isolated target prep chamber
- Rotatable polarization axis
- Ultra-low false instrumental asymmetry



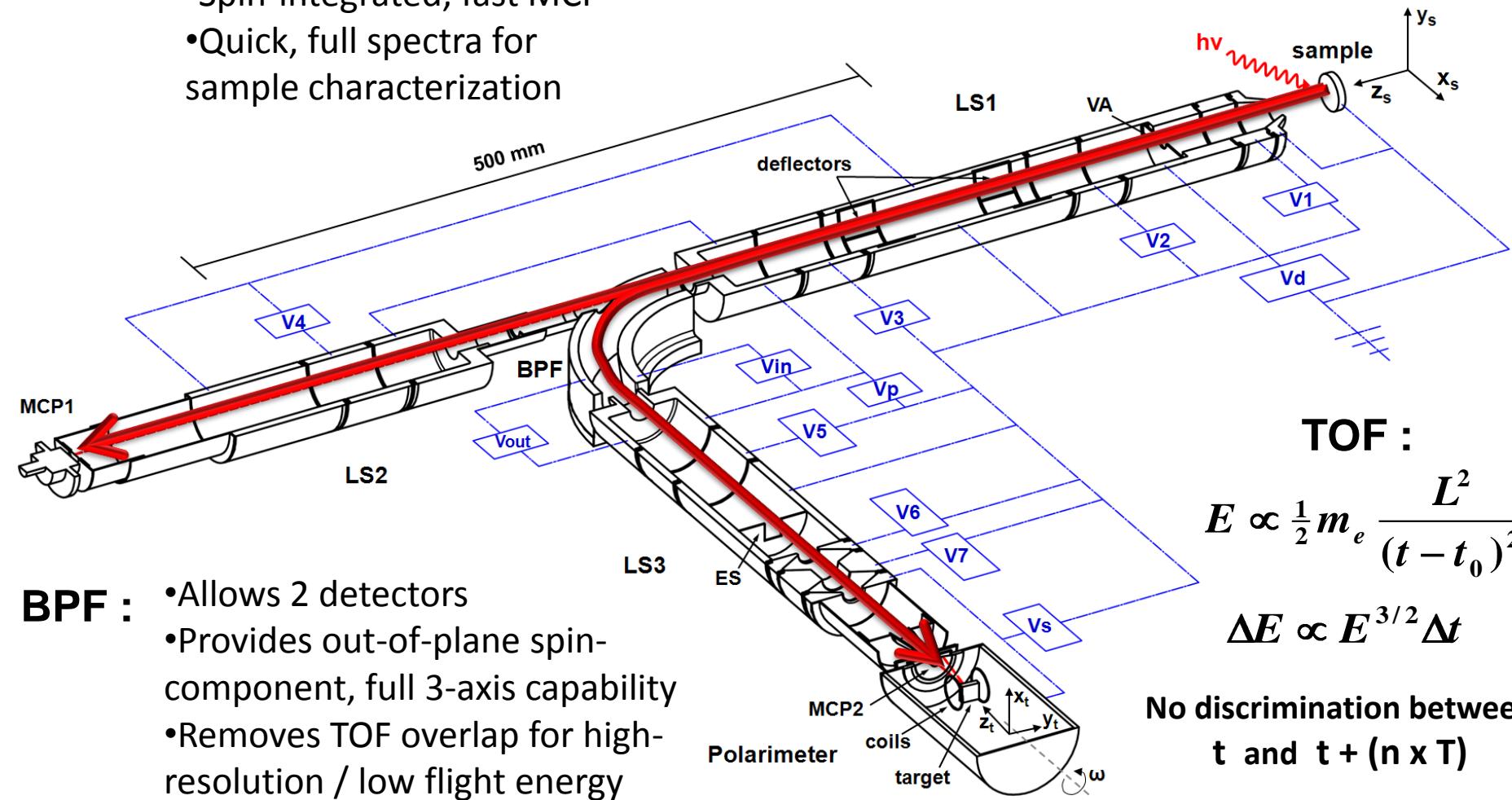


Full TOF lens system

2 modes of operation:

- “M1” :**
- Straight path
 - Spin-integrated, fast MCP
 - Quick, full spectra for sample characterization

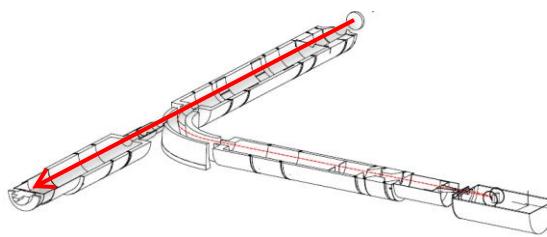
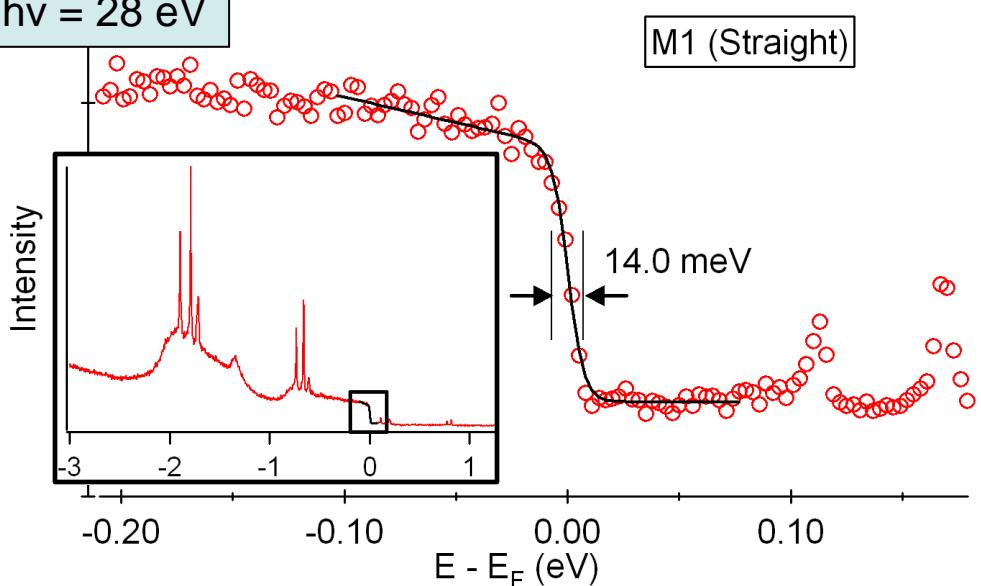
- “M2” :**
- Spin polarimeter
 - High-res, detailed spin-resolution
 - 90° spherical bandpass filter (BPF)





Energy resolution performance: M1 and M2

W(110)
 $h\nu = 28$ eV



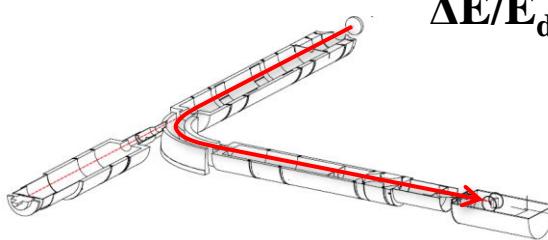
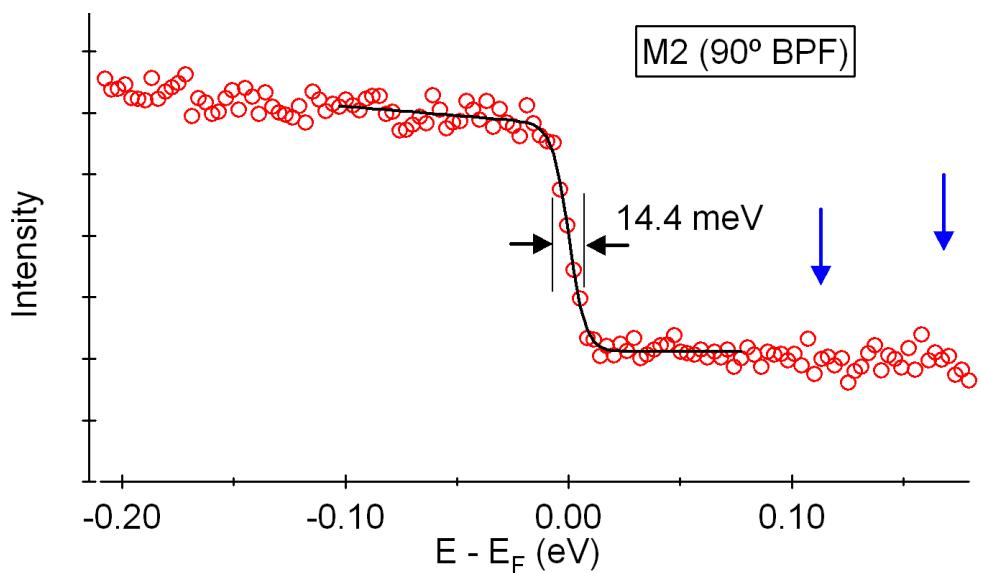
$$\Delta E_{\text{tot.}} \sim 14 \text{ meV}$$

$$\Delta E_{h\nu} \sim 10 \text{ meV}$$

$$\Delta E_{4kT} \sim 4 \text{ meV}$$

$$\Delta E_{\text{TOF}} \sim 9 \text{ meV}$$

$$\Delta E/E_d > 1000$$



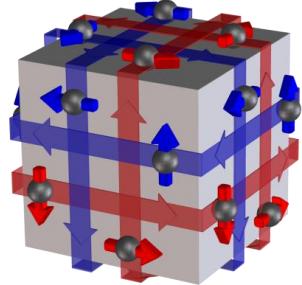
Low drift energy = high resolution

BPF = no overlap

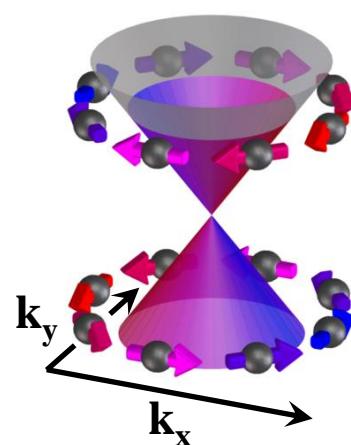
$h\nu$ rep. rates over 10 MHz

Spin texture of topological insulators

real-space



k -space



First measured spin polarizations < **20%**

- ~10% ($\text{Bi}_{1-x}\text{Sb}_x$) D. Hsieh, et al. *Science* (2009)
- ~20% (Bi_2Te_3) D. Hsieh, et al. *Nature* (2009)

Experimental literature range ~ **10 – 75%**

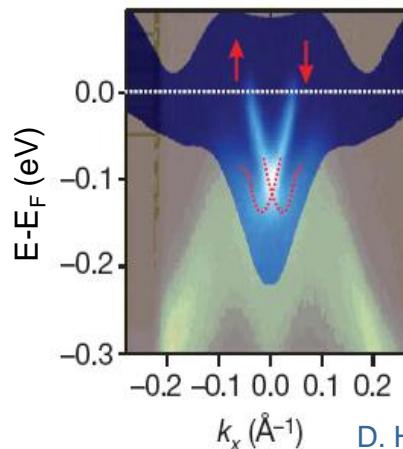
- ~10% (Bi_2Se_3 thin film) T. Hiramura, et al. *PRB* (2010)
- ~60% (Bi_2Te_3) S. Souma, et al. *PRL* (2011)
- ~60% (Bi_2Te_3) S.-Y. Xu, et al. *arxiv:1101.3985* (2011)
- ~75% (Bi_2Se_3) Z.-H. Pan, et al. *PRL* (2011)

First principals calcs ~ **50%**

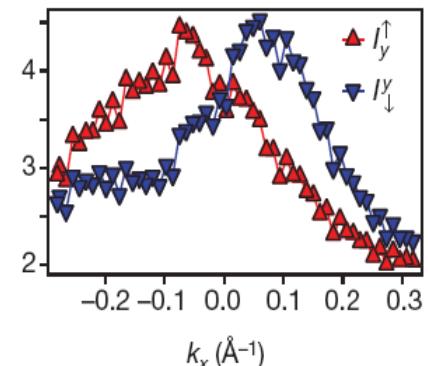
O. Yazyev, et al. *PRL* (2010)

Full understanding, characterization
necessary for device development

Bi_2Te_3

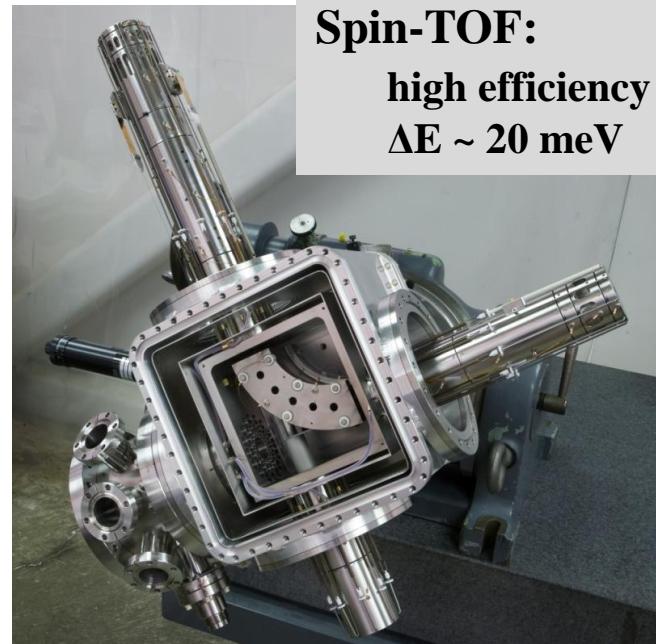


Intensity



D. Hsieh, et al. *Nature* (2009)

Spin-TOF:
high efficiency
 $\Delta E \sim 20$ meV

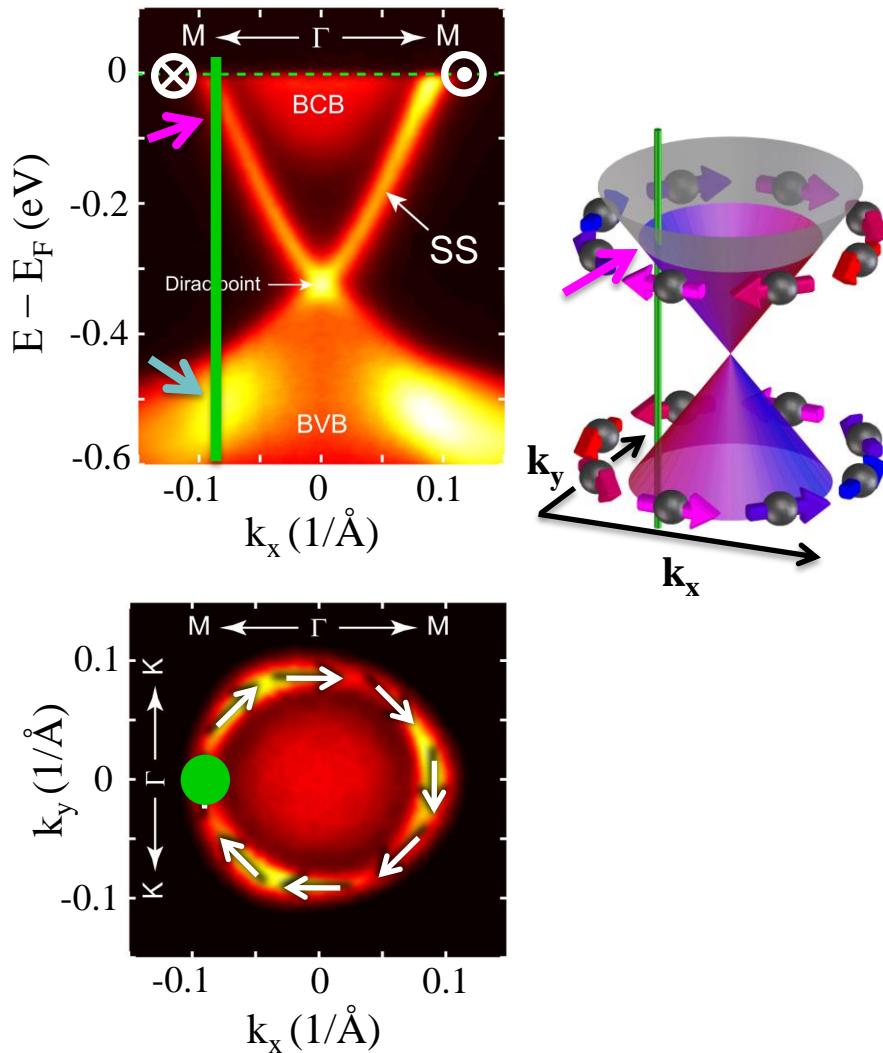


C. Jozwiak et al., *RSI* **81**, 053904 (2010)

Spin-ARPES of Bi_2Se_3

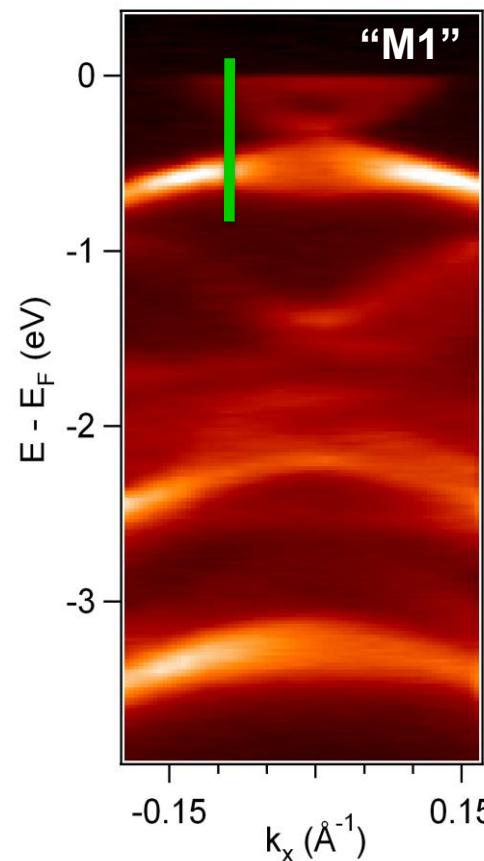
High-Res ARPES

BL10 (HERS) $h\nu = 36 \text{ eV}$



Spin-resolved ARPES

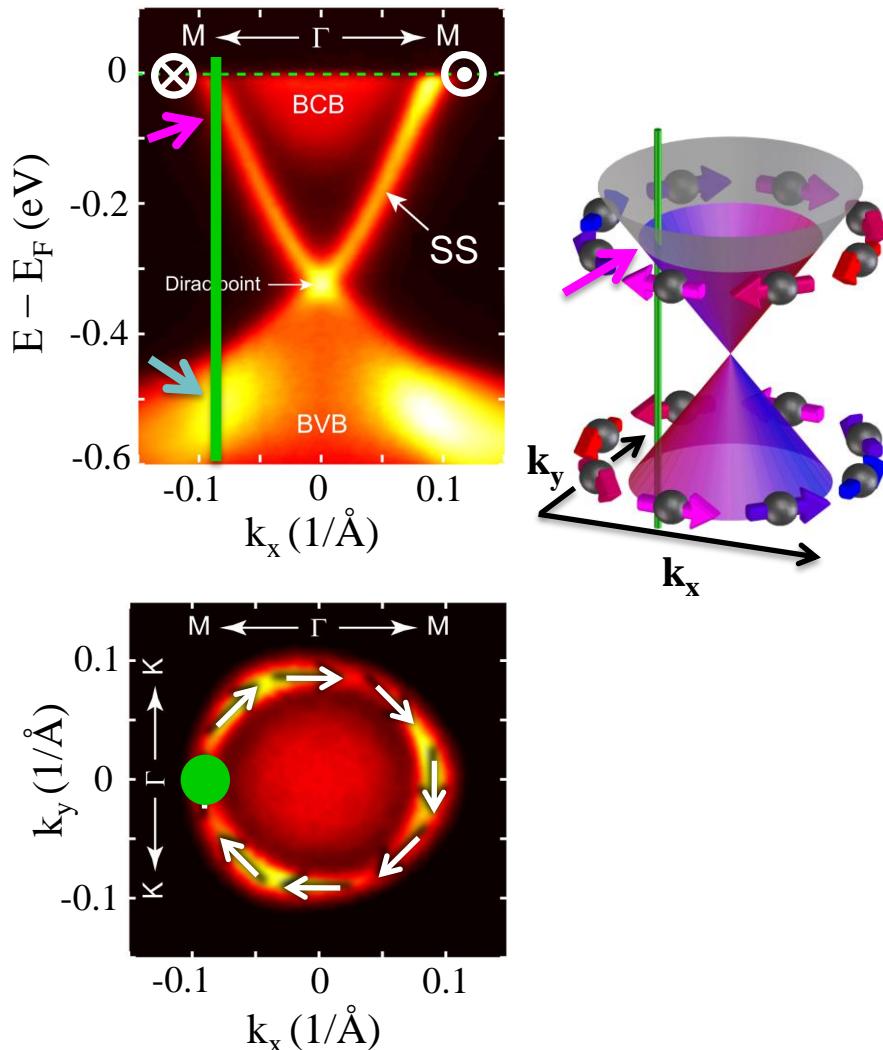
BL12.0.1 (spin-TOF) $h\nu = 36 \text{ eV}$, p-pol



Spin-ARPES of Bi_2Se_3

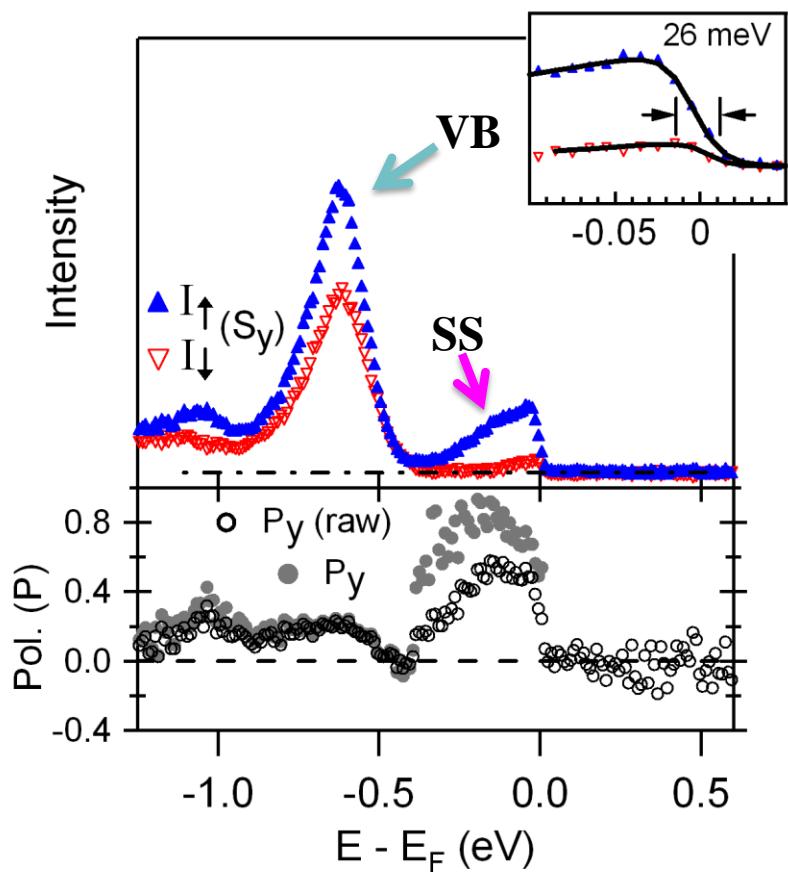
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Spin-resolved ARPES

BL12.0.1 (spin-TOF) $h\nu = 36 \text{ eV}$, p-pol



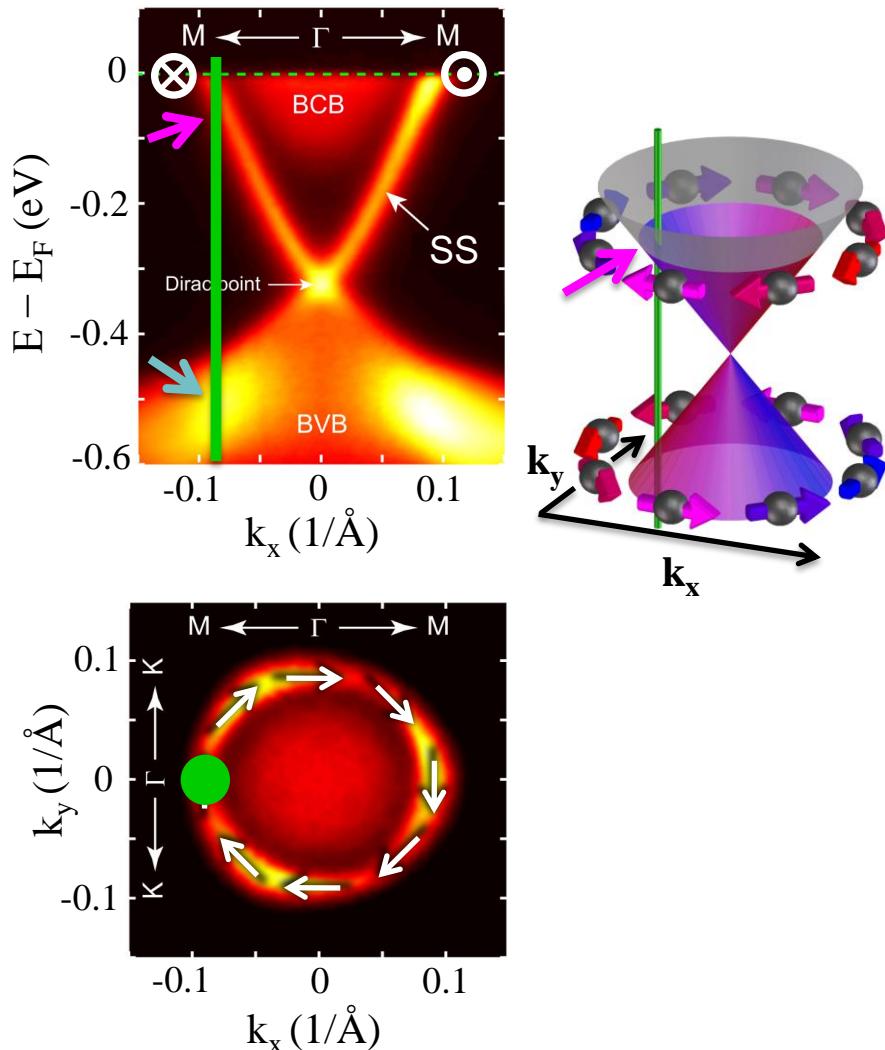
SS: $P \sim 80\%$

VB: $P \sim 20\%$

Spin-ARPES of Bi_2Se_3

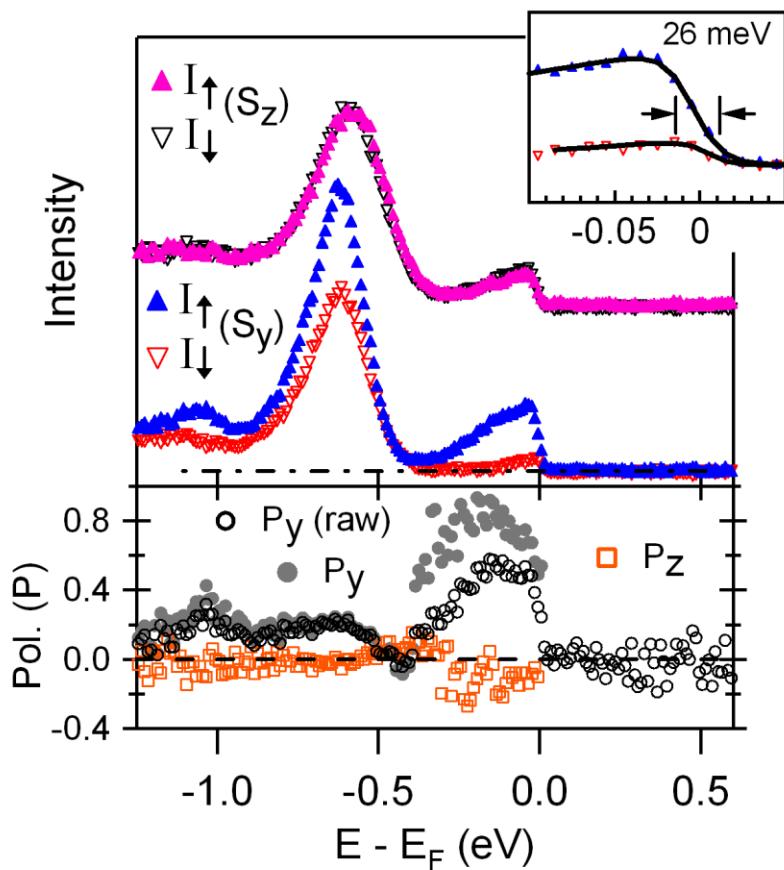
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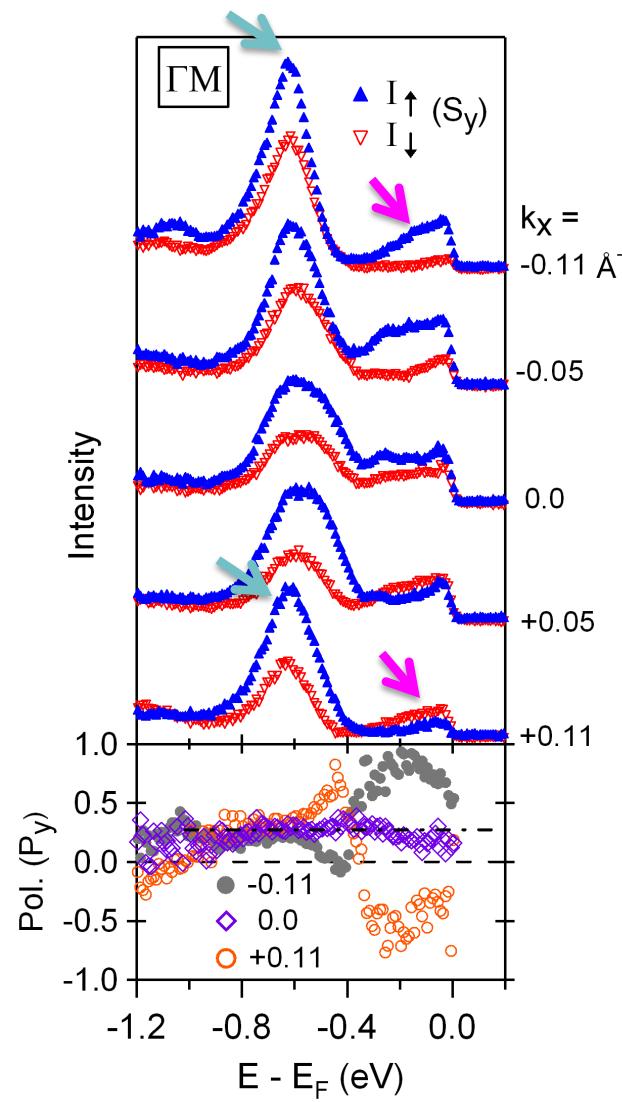
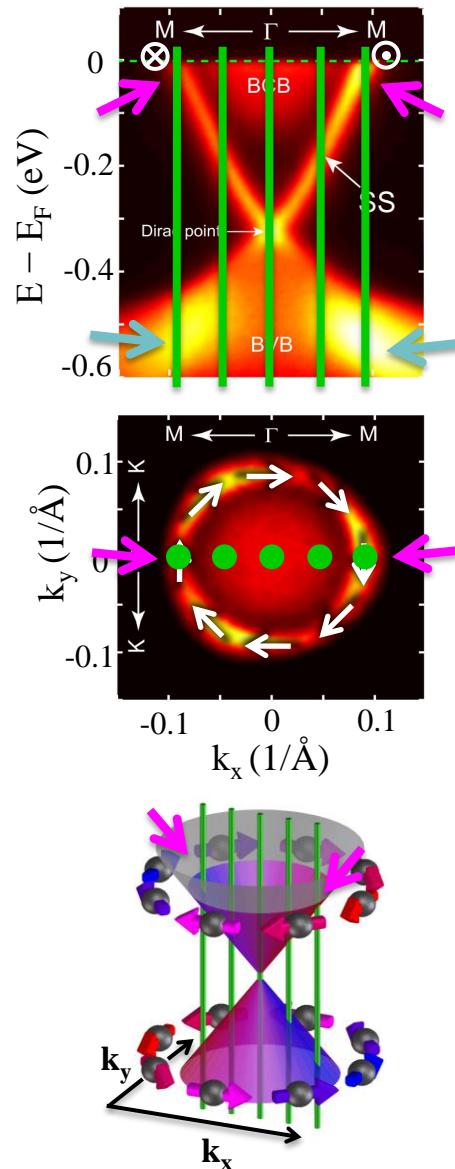
BL12.0.1 (spin-TOF) $h\nu = 36 \text{ eV}$, p-pol



SS: **P ~ 80%**

VB: **P ~ 20%**

Spin polarization \mathbf{k} -dependence



→ SS

- P dependent on \mathbf{k}
- $\mathbf{P}(\mathbf{k}) = -\mathbf{P}(-\mathbf{k})$
(Time-reversal symmetry)

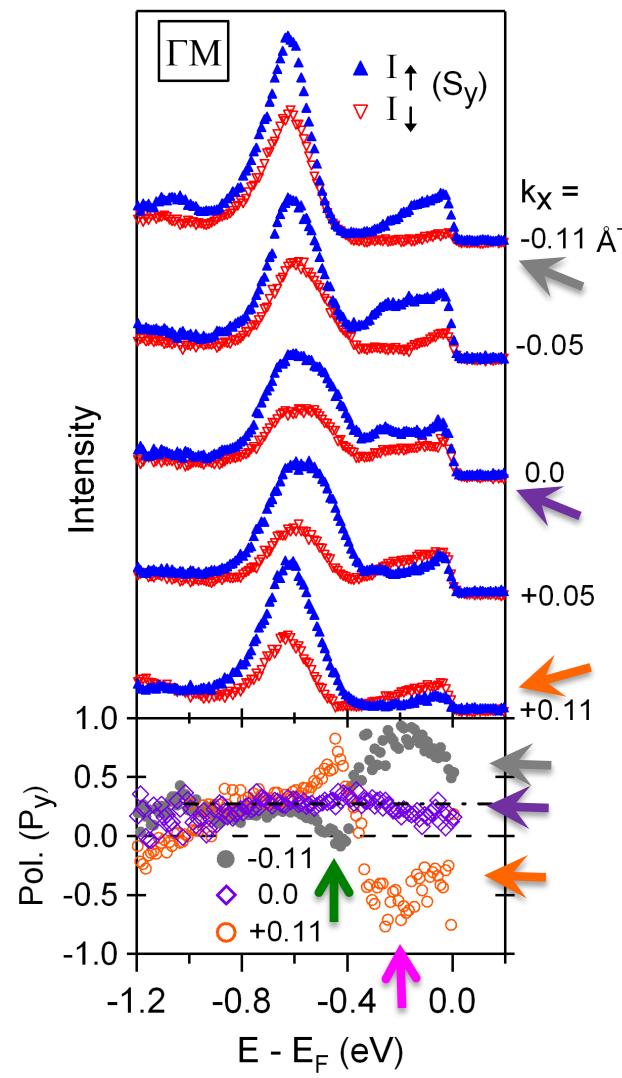
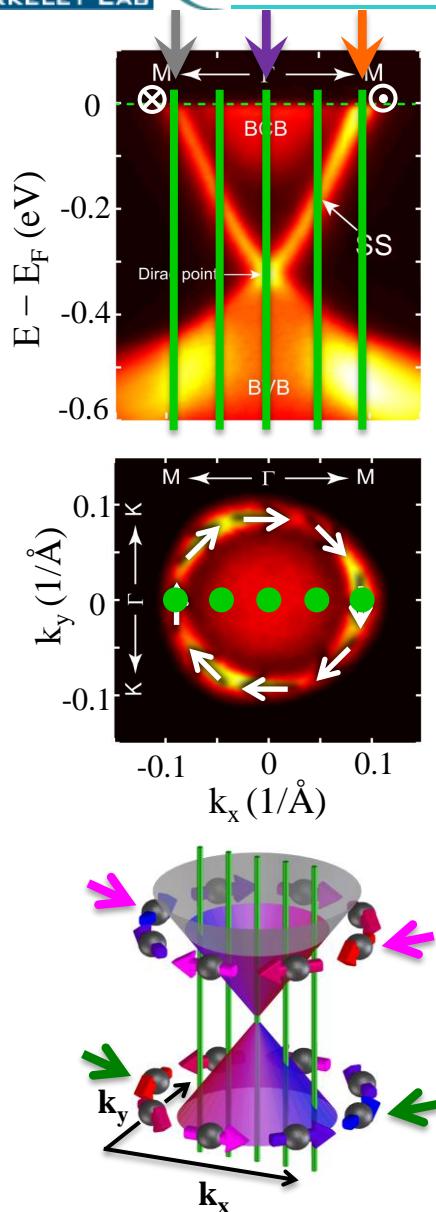
→ BB

- P independent of \mathbf{k}
- $\mathbf{P}(\mathbf{k}) \not\leq -\mathbf{P}(-\mathbf{k})$

Photoelectron polarization components:

- 1) **\mathbf{k} -dependent**
Topological physics
- 2) **\mathbf{k} -independent**
Bulk bands

Spin polarization \mathbf{k} -dependence



→ SS

- P dependent on \mathbf{k}
- $\mathbf{P}(\mathbf{k}) = -\mathbf{P}(-\mathbf{k})$
(Time-reversal symmetry)
- Reversed helicity below Dirac point

(BiTiSe_2) S.-Y. Xu *Science* (2011)

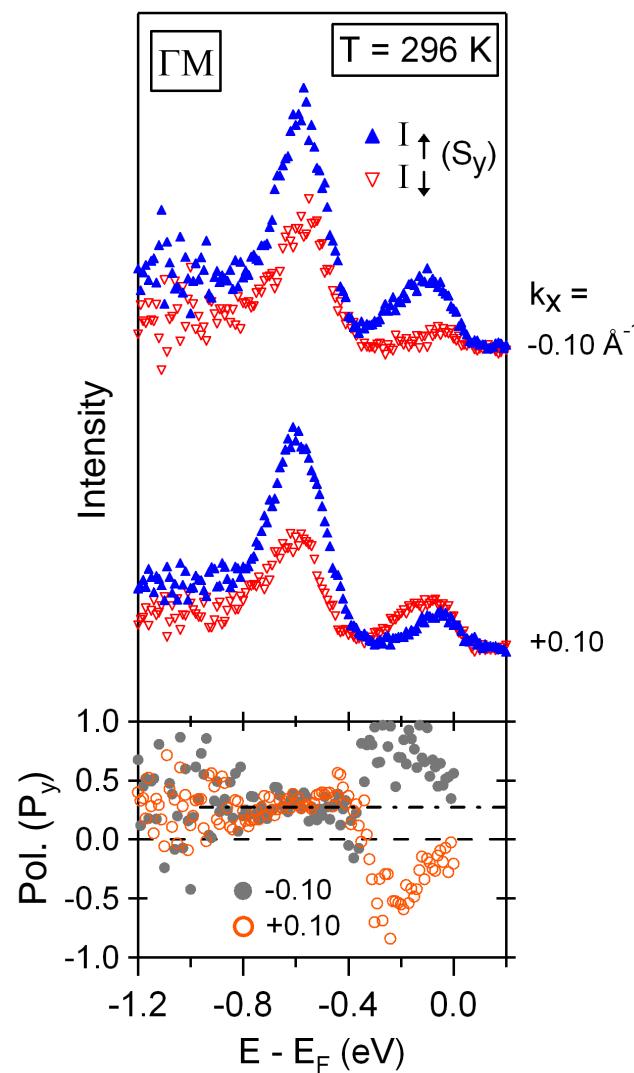
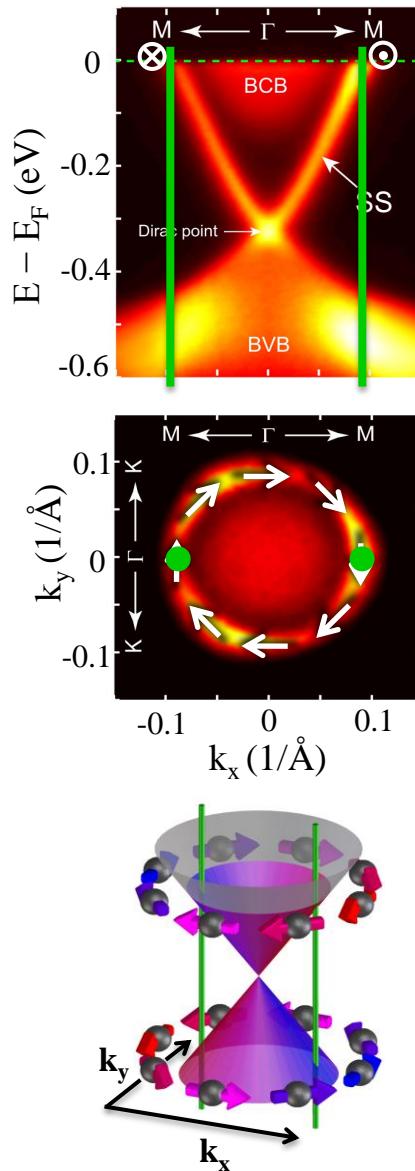
→ BB

- P independent of \mathbf{k}
- $\mathbf{P}(\mathbf{k}) \not\leq -\mathbf{P}(-\mathbf{k})$

Photoelectron polarization components:

- 1) **k-dependent**
Topological physics
- 2) **k-independent**
Bulk bands

Spin polarization at room temp.



→ SS

- P dependent on \mathbf{k}
- $\mathbf{P}(\mathbf{k}) = -\mathbf{P}(-\mathbf{k})$
(Time-reversal symmetry)

- Reversed helicity below Dirac point
- P persists at room T

→ BB

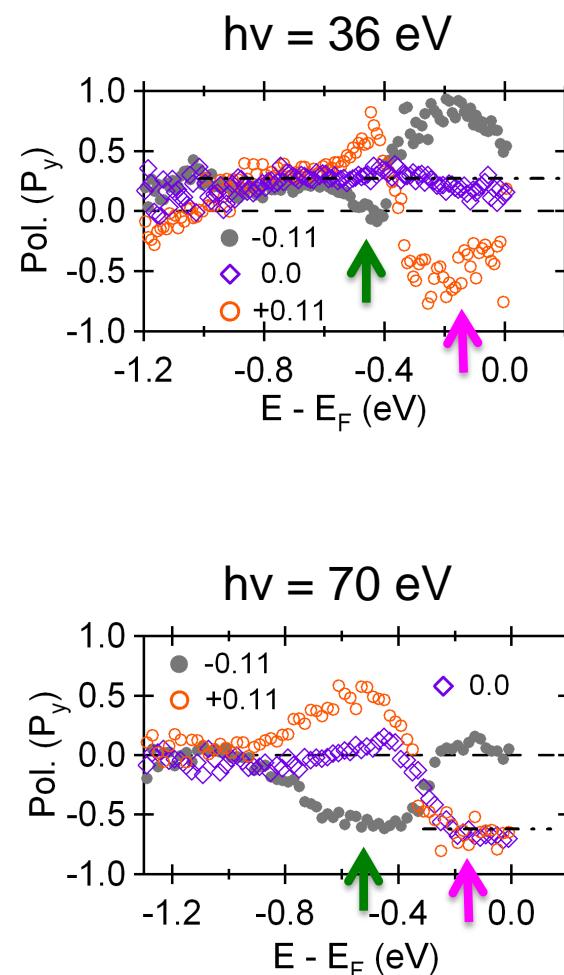
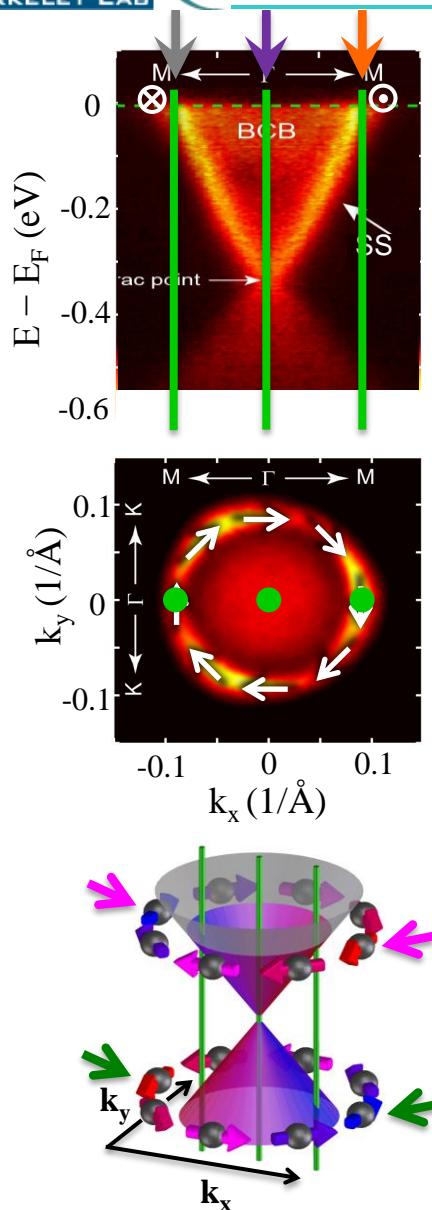
- P independent of \mathbf{k}
- $\mathbf{P}(\mathbf{k}) \not\equiv -\mathbf{P}(-\mathbf{k})$
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Photoelectron polarization components:

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Bulk bands



Spin polarization $h\nu$ -dependence



→ SS

- P dependent on \mathbf{k}
- $\mathbf{P}(\mathbf{k}) = -\mathbf{P}(-\mathbf{k})$

(Time-reversal symmetry)

- Reversed helicity below Dirac point
- P persists at room T

→ BB

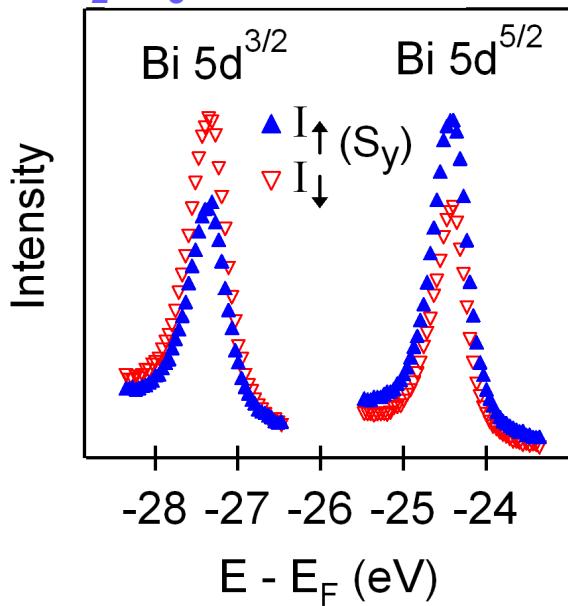
- P independent of \mathbf{k}
- $\mathbf{P}(\mathbf{k}) \not\equiv -\mathbf{P}(-\mathbf{k})$
- P persists at room T
- P dependent on $h\nu$

Photoelectron polarization components:

- 1) **k-dependent**
Topological physics
- 2) **k-independent**
Bulk bands

Spin-orbit induced photoelectron polarization

Bi_2Se_3

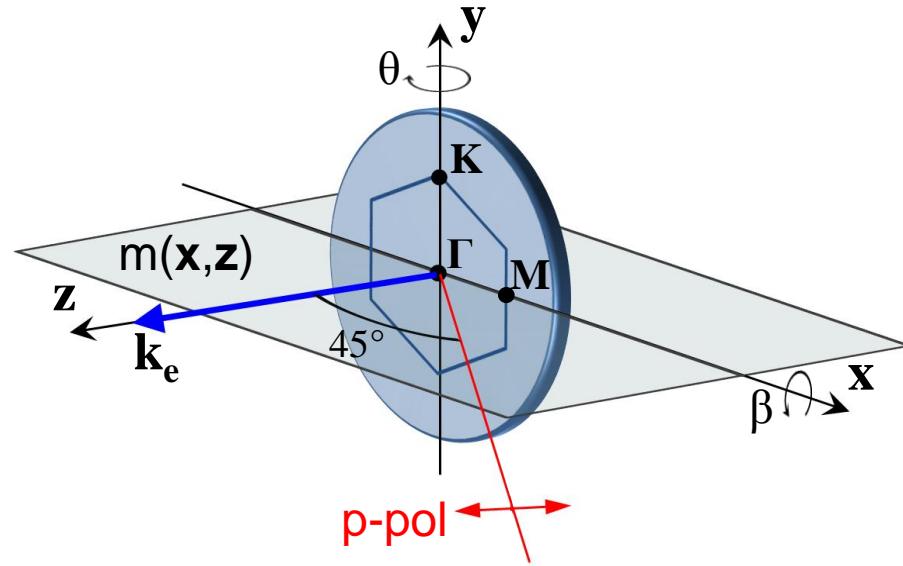


Atomic case: Cherepkov, *J Phys B* (1979)

$$\vec{P} = \frac{2\xi(\hat{k}_e \cdot \hat{\varepsilon})(\hat{k}_e \times \hat{\varepsilon})}{1 + 0.5\beta(3(\hat{k}_e \cdot \hat{\varepsilon})^2 - 1)}$$

ξ : due to interference of $\ell-1$ and $\ell+1$ phase shifts

Dependent on: geometry, photon energy and polarization



Atoms:

Theory:

C.M. Lee, *PRA* **10**, 1598 (1974)
Cherepkov, *J Phys B* **12**, 1279 (1979)

Experiment:

(Xe) Heinzmann, *PRL* **42**, 1603 (1979)
(Xe) Schonhense, *PRL* **44**, 640 (1980)

Solid, core:

Experiment:

(Cu 3p) Roth, *PRL* **73**, 1963 (1994)
(W 4f) Rose, *PRB* **53**, 1630 (1996)
(Pt 4d,f) Yu, *PRB* **77**, 193409 (2008)

Solid, VB:

Theory:

Tamura, *SSC* **79**, 989 (1991)
Tamura, *EPL* **16**, 695 (1991)

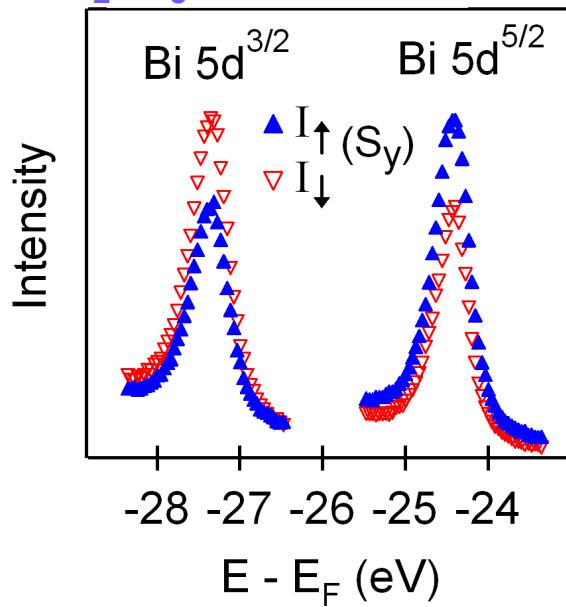
Experiment (Pt, Au):

Schmiedeskamp, *APA* **53**, 418 (1991)
Irmer, *PRB* **45**, 3849 (1992)
Johnson, *Rep. Prog. Phys.* **60**, 1217 (1997)

Relativistic one-step model calc.

Spin-orbit induced photoelectron polarization

Bi_2Se_3

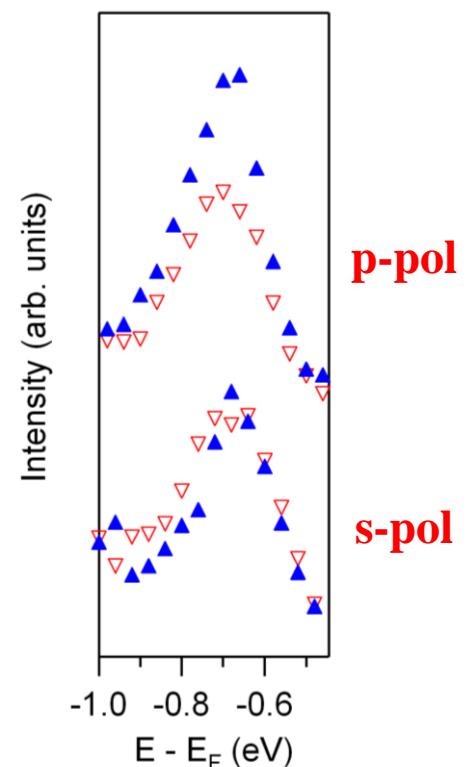
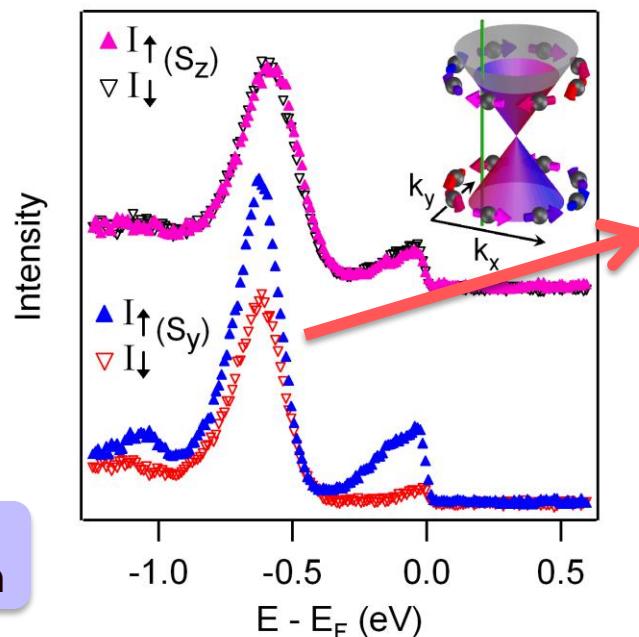
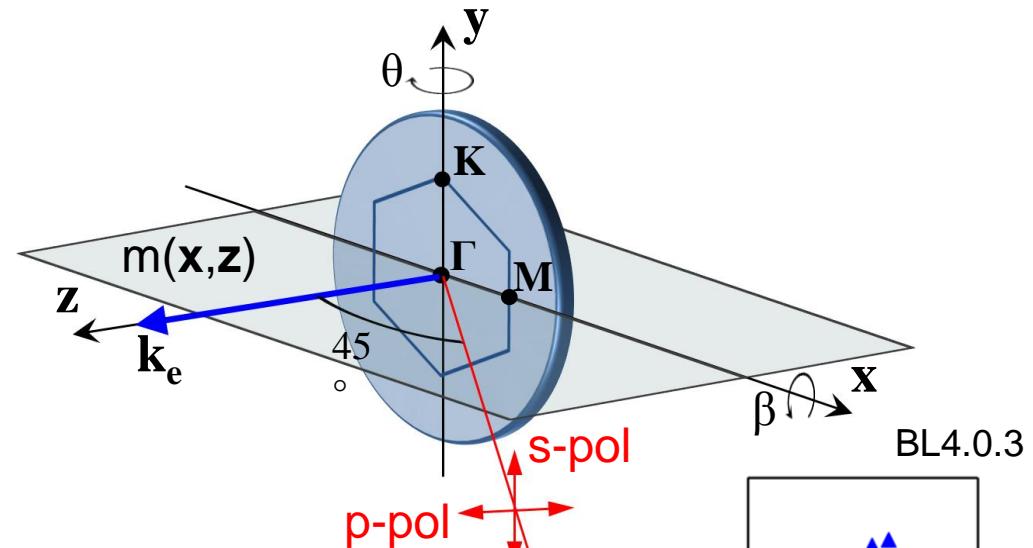


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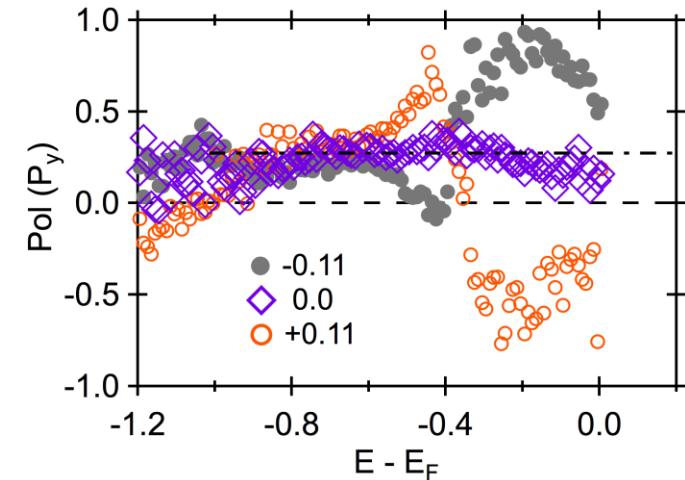


Conclusions

Efficient spin-resolved spectrometer by combining low-energy exchange scattering and TOF techniques

Thorough spin-ARPES study of 3D topological insulator, Bi_2Se_3

- Photoelectron polarization has 2 components
 - (1) **k -dependent** ($P(k) = -P(-k)$)
 - Topological spin texture
 - High $P \sim 80\%$
 - Persists at room temperature
 - Reversed helicity below Dirac point
 - (2) **k -independent**
 - Also spin-orbit induced
 - Dependent on geometry, photon energy and polarization
(i.e. not just spin polarization of initial state)
- Photoelectron polarization \neq initial state polarization



(Au) Henk, *PRB* **68**, 165416 (2003)
(graphene) Kuemmeth, *PRB* **80**, 241409(R) (2009)